

### Single Stage Amplifier

### Outline

### **1. Common-Source Amplifier**

- 2. Common-Source Amp with Source Degeneration
- 3. Common-Drain Amplifier
- 4. Common-Gate Amplifier
- 5. Cascode Amplifier

### Vision

- An important part of a designer's job is to use proper approximations so as to create a simple mental picture of a complicated circuit.
- The intuition thus gained makes it possible to formulate the behavior of most circuits by inspection rather than by lengthy calculations

### **Basic Concepts**

• The input-output characteristic of an amplifier is generally a nonlinear function

$$y(t) \approx \alpha_0 + \alpha_1 x(t) + \alpha_2 x^2(t) + \dots + \alpha_n x^n(t) \qquad x_1 \le x \le x_2$$

• For a sufficiently narrow range of x

 $y(t) \approx \alpha_0 + \alpha_1 x(t)$ ,  $\alpha_0$ : operation point,  $\alpha_1$ : small signal gain

- As *x*(*t*) increases in magnitude, higher order terms manifest themselves, leading to nonlinear distortion.
- Input-output characteristic of a nonlinear system



### Analog Design Octagon

• Analog design octagon



### Common Source Stage (I)



$$V_{in} \leq V_{TH} \implies V_{out} = V_{DD}$$

• M1 in the saturation region (Let  $V_{TH} \leq V_{in} \leq V_{in1} \implies V_{in} - V_{TH} \leq V_{out}$ ) - To find  $V_{in1}$  1 W (

$$V_{in1} - V_{TH} = V_{DD} - R_D \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (V_{in1} - V_{TH})^2$$

• M1 in the triode region  $(V_{in} > V_{in1})$ 

$$V_{out} = V_{DD} - R_D \frac{1}{2} \mu_n C_{ox} \frac{W}{L} \Big[ 2 (V_{in1} - V_{TH}) V_{out} - V_{out}^2 \Big]$$

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### Common Source Amplifier (II)



Since the transconductance drops in the triode region, (the r<sub>o</sub> also becomes smaller), we usually ensure that

$$V_{out} > V_{in} - V_{TH} \qquad \text{As} \quad V_{out} = V_{DD} - R_D \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (V_{in1} - V_{TH})^2$$
$$\Rightarrow \quad \frac{\partial V_{out}}{\partial V_{in}} = -R_D \mu_n C_{ox} \frac{W}{L} (V_{in1} - V_{TH}) = -g_m R_D$$
$$\Rightarrow \quad A_v = -g_m R_D$$

• Since  $g_m$  itself varies with the input signal, the gain of the circuit changes substantially if the signal swing is large.

### Common Source Amplifier (III)



• To take channel length modulation effect into account :

$$V_{out} = V_{DD} - R_D \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (V_{in1} - V_{TH})^2 (1 + \lambda V_{out})$$

• We have

$$\frac{\partial V_{out}}{\partial V_{in}} = -R_D \mu_n C_{ox} \frac{W}{L} (V_{in1} - V_{TH}) (1 + \lambda V_{out}) - R_D \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (V_{in1} - V_{TH})^2 \lambda \frac{\partial V_{out}}{\partial V_{in}}$$

• As

$$I_{D} \approx \frac{1}{2} \mu_{n} C_{ox} \frac{W}{L} (V_{in1} - V_{TH})^{2} \implies A_{v} = -R_{D} g_{m} - R_{D} I_{D} \lambda A_{v} \implies A_{v} = -\frac{g_{m} R_{D}}{1 + R_{D} \lambda I_{D}}$$
$$\lambda I_{D} = \frac{1}{r_{O}} \implies A_{v} = -g_{m} \frac{r_{O} R_{D}}{r_{O} + R_{D}} = -g_{m} (r_{O} \parallel R_{D})$$

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### Design Trade-off



• To maximize gain

$$A_{v} = -\sqrt{2\mu_{n}C_{ox}}\frac{W}{L}I_{D}\frac{V_{RD}}{I_{D}} = -\sqrt{2\mu_{n}C_{ox}}\frac{W}{L}\frac{V_{RD}}{\sqrt{I_{D}}}$$

- − Increase W/L → greater device capacitance ( $Gain \leftrightarrow BW$ )
- Higher  $V_{RD} \rightarrow$  smaller voltage swing ( Gain  $\leftrightarrow$  Voltage swing )
- − Reduce  $I_D$  while  $V_{RD}$  is constant → larger RC time constant at the output node ( *Gain* ↔ *BW* )

### Diode Connected Load

 In many CMOS technologies, it is difficult to fabricate resistors with tightly controlled values or a reasonable size. Replace R<sub>D</sub> with a MOS transistor.



• Diode connected : gate and drain shorted  $\rightarrow V_{DS} = V_{GS} > V_{GS} - V_{TH} \rightarrow$ the transistor always in saturation region.



### CS Stage + Diode Connected Load



- If the variation of η with the output voltage is neglected, the gain is independent of the bias current and voltages (so long as M<sub>1</sub> stays in saturation).
- Input-output characteristics of a CS stage with diode connected load.
- Operated at point A.



### CS Stage + Diode-Connected PMOS

- Example :

If  $A_v = 10$ ,  $V_{GS1} - V_{TH1} = 200 \text{ mV}$ ,  $\rightarrow V_{GS2} - V_{TH2} = 2 \text{ V}$ ,  $V_{TH2} = 0.7 \text{ V} \rightarrow V_{GS2} = 2.7 \text{ V}$ 

 $\rightarrow V_{omax} = V_{DD} - V_{GS2} \rightarrow$  Trade-off between gain and output swing

• To take the effect of channel length modulation effect into account

$$A_{v} \approx -g_{m1} \left( \frac{1}{g_{m2}} \parallel r_{o1} \parallel r_{o2} \right)$$

### CS Stage + Current Source Load

 For resistor or diode connected load, increasing the load resistance limits the output voltage swing → CS stage with current source load.



- The output bias voltage of the circuit needs a feedback loop to force V<sub>out</sub> to a known value.
- If  $A_v \uparrow \to L \uparrow \to W \uparrow$  (for constant I)  $\to C_{load} \uparrow \to Gain-Bandwidth Trade-off$
- Keep W constant,  $L \uparrow \rightarrow V_{DSmin} \uparrow \rightarrow V_{out,swing} \downarrow$

### CS Stage + Triode Load



• The gate of M2 is biased at a sufficiently low level, ensuring the load is in deep triode region for all output voltage swings.

$$V_{DD} - V_b - V_{TH} > V_{DD} - V_{out} \implies V_{out} - V_{TH} > V_b$$
$$R_{on2} = \frac{1}{\mu_p C_{ox} (W/L)_2 (V_{DD} - V_b - |V_{THP}|)}$$

- Consume less voltage headroom than diode connected devices.
- Drawback
  - $R_{on2}$  depends on  $\mu_p C_{ox}$ ,  $V_b$ , and  $V_{THP}$ , which vary with process and Temp.
  - Difficult to use.

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### CS Stage + Source Degeneration (I)

Common source Gain

$$V_{out} = -I_D R_D \implies A_v = \frac{\partial V_{out}}{\partial V_{in}} = -\frac{\partial I_D}{\partial V_{in}} R_D = -G_m R_D$$

- Improve the linearity of the gain amplifier
  - Higher linearity, Lower gain

 $G_m$ : equivalent transconductance of circuit

 $g_m$ : transconductance of MOS



I<sub>D</sub>

$$V_{in} \rightarrow I_{D} = f(V_{GS}) \Rightarrow G_{m} = \frac{\partial I_{D}}{\partial V_{in}} = \frac{\partial f}{\partial V_{GS}} \frac{\partial V_{GS}}{\partial V_{in}} \quad V_{in} \Rightarrow I_{1} + V_{1} + V_{1}$$

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### CS Stage + Source Degeneration (II)

 To take the body effect and channel length modulation effect into account



### Formulate Gain by Inspection

• Magnitude of gain as the resistance seen at the drain node divided by the total resistance in the source path



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### CS Stage + Source Degeneration (III)



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• By Inspection

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#### **Chih-Cheng Hsieh**

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### CS Stage + Source Degeneration (IV)



Voltage gain with r<sub>o</sub> & g<sub>mb</sub>

$$\frac{V_{out}}{V_{in}} = -\frac{g_m r_O R_D}{R_D + R_S + r_O + (g_m + g_{mb}) R_S r_O} 
= -\frac{g_m r_O}{R_S + r_O + (g_m + g_{mb}) R_S r_O} \cdot \frac{R_D [R_S + r_O + (g_m + g_{mb}) R_S r_O]}{R_D + R_S + r_O + (g_m + g_{mb}) R_S r_O} 
= -G_{meff} R_O = -G_{meff} \{R_D \| [R_S + r_O + (g_m + g_{mb}) R_S r_O] \}$$

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### CS Stage + Source Degeneration (V)

•  $I_0 = \text{constant}, I(R_s) = \text{constant}, \text{small-signal voltage drop across } R_s = 0$ 



$$A_{v} = -\frac{g_{m}r_{O}}{R_{s} + [1 + (g_{m} + g_{mb})R_{s}]r_{O}} \{R_{s} + [1 + (g_{m} + g_{mb})R_{s}]r_{O}\}$$
$$= -g_{m}r_{O} = \text{ intrinsic gain, independent of } R_{s}$$

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### CD Stage: Source Follower (I)

- The source follower can operate as a voltage buffer High input impedance, low output impedance.
- Gain  $\approx$  1, but not equal to 1 even with  $R_s$  = infinity.





$$\frac{1}{2}\mu_{n}C_{ox}\frac{W}{L}(V_{in}-V_{TH}-V_{out})^{2}R_{S} = V_{out}$$
$$\frac{\partial V_{out}}{\partial V_{in}} = \frac{\mu_{n}C_{ox}\frac{W}{L}(V_{in}-V_{TH}-V_{out})R_{S}}{1+\mu_{n}C_{ox}\frac{W}{L}(V_{in}-V_{TH}-V_{out})R_{S}(1+\eta)}$$

$$g_{m} = \mu_{n}C_{ox}\frac{W}{L}(V_{in} - V_{TH} - V_{out})$$
$$A_{v} = \frac{g_{m}R_{s}}{1 + (g_{m} + g_{mb})R_{s}}$$

### CD: Small-signal equivalent circuit

 Calculate the voltage gain by small-signal equivalent circuit of source follower with body effect



# R<sub>out</sub> of Source Follower

• Body effect decrease R<sub>out</sub> of source follower



Less-than-unity voltage gain of source follower with body effect



### Source Follower with r<sub>o</sub>

• Source follower with finite channel-length modulation



$$A_{v} = \frac{\frac{1}{g_{mb}} \| r_{O1} \| r_{O2} \| R_{L}}{\frac{1}{g_{mb}} \| r_{O1} \| r_{O2} \| R_{L} + \frac{1}{g_{mb}}}$$

### Source Follower Drawback

- Voltage headroom consumption due to level shift.
- Nonlinearity
  - Nonlinear dependence of  $V_{TH}$  upon the source potential.
  - $-r_o$  of the transistor also changes substantially with  $V_{DS}$ .
- PMOS source follower with no body effect



Higher output impedance using PMOS source follower.

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### **CG: Common-Gate Stage**

 If M<sub>1</sub> is saturated, the V<sub>out</sub> can be expressed as ξ R<sub>D</sub>  $V_{out} = V_{DD} - \frac{1}{2} \mu_n C_{ox} \frac{W}{I} (V_b - V_{in} - V_{TH})^2 R_D$  $\frac{\partial V_{out}}{\partial V_{in}} = -\mu_n C_{ox} \frac{W}{L} \left( V_b - V_{in} - V_{TH} \right) \left( -1 - \frac{\partial V_{TH}}{\partial V_{\cdot}} \right) R_D$ For  $\frac{\partial V_{TH}}{\partial V_{in}} = \frac{\partial V_{TH}}{\partial V_{SP}} = \eta$  $\frac{\partial V_{out}}{\partial V_{i}} = \mu_n C_{ox} \frac{W}{L} (V_b - V_{in} - V_{TH}) (1+\eta) R_D = g_m (1+\eta) R_D$ Ş R<sub>D</sub> Body effect increases the equivalent g<sub>m</sub> of the stage.  $v_{in} \bigcirc^+$ M <sub>1</sub> Body effect deceases the input impedance of CG.

$$Z_{in} = \frac{1}{g_m + g_{mb}} = \frac{1}{g_m (1 + \eta)}$$

### CG Stage- Input Impedance

• By taking into account both the output impedance of the transistor  $r_o$ , find the input impedance  $Z_{in}$ :



• For  $R_D = 0$ , same as source follower

$$Z_{in} = \frac{V_X}{I_X} = \frac{r_O}{1 + (g_m + g_{mb})r_O} = \frac{1}{g_m + g_{mb} + 1/r_O} = r_O \|\frac{1}{g_m}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{mb}}\|\frac{1}{g_{$$

• For  $R_D = \infty$ ,  $Z_{in} = \infty$ 

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### CG Stage- Output Impedance

 The output impedance is similar to that of a common source gain stage with source degeneration. R<sub>s</sub> is the impedance of signal source.



$$R_{out} = \{ [1 + (g_m + g_{mb})r_O]R_S + r_O \} || R_D$$

### CG Stage- Voltage gain

 Voltage gain is similar to CS + Source degeneration, it's slightly higher due to body effect



$$\frac{V_{out}}{V_{in}} = \frac{1 + (g_m + g_{mb})r_o}{r_o + (g_m + g_{mb})r_o R_s + R_s + R_D} R_D = \frac{1 + (g_m + g_{mb})r_o}{r_o + (g_m + g_{mb})r_o R_s + R_s} \frac{[r_o + (g_m + g_{mb})r_o R_s + R_s]R_D}{r_o + (g_m + g_{mb})r_o R_s + R_s + R_D}$$
$$= \frac{1 + (g_m + g_{mb})r_o}{r_o + (g_m + g_{mb})r_o R_s + R_s} R_{out} \frac{V_{out}}{V_{in}} \bigg|_{CS+SD} = \frac{g_m r_o}{r_o + (g_m + g_{mb})r_o R_s + R_s} \frac{[r_o + (g_m + g_{mb})r_o R_s + R_s]R_D}{r_o + (g_m + g_{mb})r_o R_s + R_s} \frac{[r_o + (g_m + g_{mb})r_o R_s + R_s]R_D}{r_o + (g_m + g_{mb})r_o R_s + R_s}$$

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### CAS: Cascode Stage (I)

Cascade of a CS stage and a CG stage → a high output impedance.



• Without consideration of  $r_{0}$ , The voltage gain is independent of the transconductance and body effect of M2.

### CAS: Cascode Stage (II)

• If both M<sub>1</sub> and M<sub>2</sub> operate in saturation.

$$G_{m} \approx g_{m1}$$

$$R_{out} = [1 + (g_{m2} + g_{mb2})r_{O2}]r_{O1} + r_{O2}$$

$$R_{out} \approx (g_{m2} + g_{mb2})r_{O2}r_{O1}$$

$$A_{v} = -(g_{m2} + g_{mb2})r_{O2}g_{m1}r_{O1}$$



• The maximum voltage gain is roughly equal to the square of the intrinsic gain of the transistors

### NMOS CAS Amp + PMOS CAS Load

- Cascode as a constant current source with high output impedance
- The maximum output swing is equal to

$$V_{out,swing} = V_{DD} - V_{DS1} - V_{DS2} - V_{SD3} - V_{SD4}$$

$$R_{out} = \{ \left[ 1 + \left( g_{m2} + g_{mb2} \right) r_{O2} \right] r_{O1} + r_{O2} \} \\ \| \{ \left[ 1 + \left( g_{m3} + g_{mb3} \right) r_{O3} \right] r_{O4} + r_{O3} \} \right]$$

$$A_{v} \approx -g_{m1} \left[ \left( g_{m2} r_{O2} r_{O1} \right) \| \left( g_{m3} r_{O3} r_{O4} \right) \right]$$



### Folded Cascode

- A PMOS-NMOS combination.
- The total bias current in this case must be higher to achieve comparable performance.



## R<sub>out</sub> of Folded-Cascode



$$R_{out} = \left[1 + (g_{m2} + g_{mb2})r_{O2}\right](r_{O1} || r_{O3}) + r_{O2}$$

**Analog IC Analysis and Design** 

### **Designer's Intuition**

- Simulation is essential because the behavior of short-channel MOSFET can't be predicted accurately by hand calculations.
- Don't avoids a simple and intuitive analysis of the circuit and skip the task of gaining inside, you can't interpret the simulate results intelligently.
- Don't let the computer think for you!